Carrier Dynamics and Multiple Exciton Generation in Nanocrystals: Applications to 3rd Generation Solar Photon Conversion

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<table>
<thead>
<tr>
<th>Name</th>
<th>Contributions</th>
</tr>
</thead>
<tbody>
<tr>
<td>Randy Ellingson</td>
<td>Exciton dynamics, MEG</td>
</tr>
<tr>
<td>Matt Beard</td>
<td>THz spectroscopy, MEG</td>
</tr>
<tr>
<td>Justin Johnson (PD)</td>
<td>SF, Exciton dynamics, MEG</td>
</tr>
<tr>
<td>Kelly Knutsen (PD)</td>
<td>Exciton dynamics, MEG (Si)</td>
</tr>
<tr>
<td>Joseph Luther (GS)</td>
<td>MEG photocurrent, QD arrays</td>
</tr>
<tr>
<td>Jim Murphy (GS)</td>
<td>THz Spectroscopy, QD arrays</td>
</tr>
<tr>
<td>Pingrong Yu</td>
<td>MEG Solar Cells</td>
</tr>
<tr>
<td>Mark Hanna</td>
<td>Thermodynamic Efficiencies</td>
</tr>
<tr>
<td>Sasha Efros (NRL)</td>
<td>Theory of MEG</td>
</tr>
<tr>
<td>Andrew Shabaev (NRL)</td>
<td>Theory of MEG</td>
</tr>
<tr>
<td>Josef Michl (UCB)</td>
<td>Singlet Fission (SF)</td>
</tr>
<tr>
<td>Mark Ratner (NWU)</td>
<td>Singlet Fission (Theory)</td>
</tr>
</tbody>
</table>

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Consequences of Size Quantization

- Large blue shift of absorption edge
- Discrete energy levels/structured absorption and photoluminescence spectra
- Dramatic variation of optical and electronic properties
- Enhanced photoredox properties for photogenerated electrons and holes
- Greatly enhanced exciton absorption at 300 K
- Conversion of indirect semiconductors to direct semiconductors or vice versa
- Greatly enhanced oscillator strength per unit volume (absorption coefficient
- Greatly modified pressure dependence of phase changes and direct to indirect transitions
- Greatly enhanced non-linear optical properties
- Efficient anti-Stokes luminescence

Effects on Dynamics:

- Slowed relaxation and cooling (~10X) of photogenerated hot electrons and holes (excitons)
- Conservation of crystal momentum relaxed
- Enhanced Auger processes (invoked to explain PL blinking, breaking phonon bottleneck, and multiple exciton generation)
QUANTIZATION EFFECTS

- Auger processes enhanced
- Hot exciton cooling slowed (compared to MEG)
- Crystal momentum not a good quantum number

Quantum Well

- \( n^e = 4 \)
- \( n^e = 3 \)
- \( n^e = 2 \)
- \( n^e = 1 \)

\( E_g \) (Barrier)

\( h^h = 1 \)
\( h^h = 2 \)
\( h^h = 3 \)
\( h^h = 4 \)

\( \tau_{\text{QW therm}} \approx \tau_{\text{bulk therm}} \) (Highlighted)

Bulk

- \( \tau_{\text{therm}} \) (Highlighted)

\( E_c \)
\( E_v \)

\( h^+ \) (Cavity States)

\( h^+ \) (Excitons)

\( h\nu \) (Photon Energy)

\( e^- \) (Electrons)

\( \text{Hot exciton cooling slowed (compared to MEG)} \)
Enhanced Photovoltaic Efficiency in Quantum Dot Solar Cells by Multiple Exciton Generation

Multiple Exciton Generation (MEG) is an inverse Auger process; Auger processes are enhanced in QDs: 

\[ <2P_e|\nu(r_1,r_2)|1S_e1S_e1S_h> \]

- Crystal momentum need not be conserved (not a good quantum number)
- Carrier thermalization is suppressed (phonon bottleneck)

\[ h\omega = 20 \text{ meV} \quad 100 \text{ meV} \]

\[ 1P_e \quad 1S_e \]

One photon yields two e\(^-\)–h\(^+\) pairs

Impact ionization (now called Multiple Exciton Generation (MEG))

(MEG can compete successfully with phonon emission and forward Auger processes)

Efficiency of Solar Photon Conversion

Main Process Limiting Conversion Efficiency (> 50% loss)

Excess $e^-$ kinetic energy

$E_c$

$\Delta E_e$

$E_g$

$h\nu > E_g$

Carrier relaxation/cooling (conversion of carrier kinetic energy to heat by phonon emission)

Excess $h^+$ kinetic energy

$E_v$

$\Delta E_h$

$h^+$

Hot $e^-$ Relaxation
SOLAR ELECTRICITY

Conventional PV Cell

1 e\(^-\) - h\(^+\) pair/photon

\(\eta_{\text{max}} = 32\%\)
Photovoltaic Cells

I. 1st Generation
   • Single crystal Si
   • Poly-grain Si

II. 2nd Generation (Polycrystalline Thin Film)
   • Amorphous Si
   • Thin film Si
   • CuInSe$_2$
   • CdTe
   • Dye-sensitized Photochemical Cell

III. 3rd Generation ($n_{\text{theor}} > 32\%$ Queisser-Shockley limit and low cost)
    • (High efficiency multi-gap tandem cells (here now but expensive))
    • Multiple Exciton Generation (MEG) solar cells
    • Quantum Dot Solar Cells
    • Singlet Fission Solar Cells
    • Hot electron converters
    • Intermediate Band PV
    • Photon management (upconversion and down conversion)
    • Thermophotovoltaics/thermophotonics

Photocurrent Multiplication by Impact Ionization (I.I.)

Another Way

Photocurrent Multiplication by Impact Ionization (I.I.)

1 photon yields 2 (or more) e^- - h^+ pairs

(I.I. previously observed in bulk Si, Ge, InSb, PbS, and PbSe > 30 years ago—mainly with applied electric field (avalanche photodiodes)—BUT NOT USEFUL FOR PV BULK MATERIALS
Detailed balance model

- All photons above the bandgap are absorbed.
- Photons less than the bandgap not absorbed.
- Only loss if radiative recombination.
- All photogenerated carriers are collected.

QY for carrier generation:
QY = 0  E < Eg
QY = M  MxEg < E < (M+1)Eg for M < Mmax,
where Mmax = 4/Eg

Photogenerated current:
Jg = q \int QY(E) \Gamma(E) dE

Recombination current:
J_R(V, E_g) = qg \int_{E_g}^{\infty} \frac{QY(E)E^2}{\exp\left(\frac{E - qQY(E)V}{kT}\right) - 1} dE

IV curve: J(V) = J_g - J_R(V)

Series connected Tandem Cell:
J(V) = J_1(V_1) + J_2(V_2) and V = V_1 + V_2.

Detailed Balance Efficiency Calculations

Optical Generation Quantum Yield

Eg = 0.75 eV

AM1.5G

Solar Photon Current (mA/cm^2 eV)

QY for a tandem MEG cell

M_{top} = 2
M_{bottom} = 2
Limiting Efficiency for Unconcentrated AM1.5G Spectrum (Single Bandgap)

Hanna and Nozik, JAP 100, 74510 (2006)
Single gap MEG cell efficiency increases at a faster rate under solar concentration than a normal semiconductor cell with no carrier multiplication (M=1).
Conservation of energy $E$ and momentum $\frac{hk}{2\pi}$ is fulfilled if the two dash-dotted arrows add vectorially to zero.

**QDs:** *Requirement for conservation of momentum is relaxed. Threshold should be lower.*
Because of the need to conserve momentum, and because the rate of impact ionization is much slower than the rate of phonon emission at low electron energies, impact ionization is an inefficient process in bulk semiconductors in the visible and near IR, and for Si requires UV photons.
Transmission Electron Micrograph (TEM) of PbSe Quantum Dots (also called Nanocrystals)

5 nanometers
5 x \(10^{-9}\) m
0.000005 mm

20 rows of atoms, ~ 6000 atoms, in these QDs

TEM From Andrew Norman
PbTe Arrays in HCP Configuration


TEM: Andrew Norman
Arrays of Cubic-shaped Lead Salt NCs

PbSe   NCs   PbTe

TEM: Andrew Norman
MEG DYNAMICS

Determine the photogenerated carrier density (QY) and thus MEG dynamics by: (a) measuring the free carrier absorption (IR probe) and exciton bleach (HOMO-LUMO probe); (b) measuring dynamics of multi-exciton decay vs single exciton decay, and the rise time of exciton bleaching and induced exciton absorption.

$\Delta \alpha \propto e-h$ pair (exciton) density; $1S$ bleach decay dynamics $= f(\text{multiexciton density})$; $1S$ bleach dynamics and induced exciton absorption determine carrier cooling rate and carrier multiplication rate.
Transient absorption experimental setup

- Quantronix Ti:Sapphire Amplifier
- Topas OPA
- 805 nm
- Al₂O₃
- White Light probe 440-1070 nm
- PC
- KML Ti:S Oscillator
- Sample
- Delay 1.5 ns
- Vis/IR probe 290 nm-10 µm
- Chopper
- Pump 290-2200 nm
Experimental Verification of Greatly Enhanced $e^- - h^+$ multiplication (we term Multiple Exciton Generation (MEG)) in Quantum Dots

- R.D. Schaller and V.I. Klimov, Phys. Rev. Letts, 92, 186601 (May), 2004 (PbSe QDs)
- R.J. Ellingson, M. Beard, J. Johnson, P. Yu, O. Micic, A. Shabaev, A. Efros, A.J. Nozik, Nano Letters 5, 865, 2005 (PbSe and PbS QDs; 300% QY (3 e-/photon) at 4 times $E_g$)
- Recently, MEG also found in PbTe (NREL, JACS, 128, 3241, 2006) and CdSe (LANL, APL, 2005); 7 e-/photon in PbSe! (LANL, NanoLetts, 6, 424, 2006); InAs (Van Maekelbergh, Banin, et. Al., J. Phys. Chem. C (2007)); and Si (NREL, 2007)
Exciton dynamics for different pump energies with mid-IR intraband probe (5 µ)

(a)

$\Delta \alpha$ (normalized at tail)

$E_{hv}/E_g = 5.00$

$E_{hv}/E_g = 4.66$

$E_{hv}/E_g = 4.25$

$E_{hv}/E_g = 4.05$

$E_{hv}/E_g = 3.60$

$E_{hv}/E_g = 3.25$

$E_{hv}/E_g = 1.90$

Time delay (ps)
MEG in PbX; X = Se, S, Te
(QY > 200% means 3 e-/photon are created; QY = 300% means all dots have 3 e-)

$E_g$ (HOMO - LUMO) --
- 0.91 eV
- 0.91 eV
- 0.91 eV
- 0.91 eV
- 0.91 eV
- 0.82 eV
- 0.73 eV
- 0.73
- 0.73
- PbTe - 0.91 eV
- PbS - 0.8 eV

Quantum Yield (%) vs. $E_{hv}/E_g$
Silicon Nanocrystals

- Particles 3-10 nm diameter
- Bulk bandgap 1.12 eV (~1100 nm);
- Si NC bandgaps 1.22-1.6 eV (1016 – 775 nm)

TEM image courtesy of Innovalight, Inc.
Amine soak properties

<table>
<thead>
<tr>
<th>ligand</th>
<th>$d$ (nm)</th>
<th>$\epsilon_{\text{ligand}}$</th>
<th>mobility (cm$^2$ V$^{-1}$ s$^{-1}$)</th>
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</thead>
<tbody>
<tr>
<td>butylamine</td>
<td>0.4</td>
<td>5.4</td>
<td>7.4</td>
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<tr>
<td>hydrazine</td>
<td>0.25</td>
<td>53</td>
<td>29.4</td>
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<tr>
<td>NaOH</td>
<td>0.1</td>
<td>1</td>
<td>35</td>
</tr>
<tr>
<td>ethylenediamine</td>
<td>0.4</td>
<td>16</td>
<td>47</td>
</tr>
</tbody>
</table>

Murphy, Beard, Nozik, JPC B 2006
PROPOSED NEW PHYSICS BASED ON MODEL INVOLVING:

**COHERENT SUPERPOSITION OF MULTI-EXCITON STATES IN SEMICONDUCTOR NANOCRYSTALS**

Shabaev, Efros, Nozik, Nano Lett. 6, 2856 (2006)

Other proposed models to explain MEG:


Multi-Exciton Generation by One Photon

What is the reason of such high efficiency? - Impact Ionization?

Puzzle:
- Decay time \(\sim 100\) ps (Auger process)
- Rise time \(\sim < 2-3\) ps (Inverse Auger process)

Instantaneous creation of a coherent superposition of several electron-hole pairs by a single photon
NEW MODEL FOR MEG
Coherent Superposition of Multi-Excitonic States in PbSe QDs
States with Energy Larger than Energy Gap

Electron in NC occupying 2P_e state:

\[ W_C = \frac{e^2}{|r_1 - r_2|} \]

Two states are degenerate and coupled:

\[ W_C = \langle 2P_e | \nu(r_1, r_2) | 1S_e 1S_e 1S_h \rangle \]

Kang & Wise (1997)
Coherent Superposition of Multi-Exciton States

Optical excitation of “2P_e”-”2P_h” transitions:

The efficiency of the multi-exciton generation depends on the relaxation mechanism. There is high probability that the state relaxes to the two e-h pair state.
Density matrix

Theoretical description requires:

**time dependent density matrix for:**

- Short pulse excitation
- Different relaxation mechanisms

\[
\frac{\partial \rho}{\partial t} = \frac{i}{\hbar} [\rho H]
\]

Dynamics for times: \( \Delta t \ll \tau_A \ll \tau_r \)

(Shabaev, Efros, Nozik, Nano Lett. 6, 2856 (2006))
Time Resolved THz Spectroscopy

- Measure transient THz frequency average conductivity
- Subpicosecond resolution
- Mechanistic information
- No electrical contacts

\[
\Delta E_{THz}(t, \tau) \approx \frac{-\sigma(\tau)x}{2cn\varepsilon_0} \frac{E^{Off}_{THz}(t)}{E_{THz}(t)}
\]
# Film Treatments

<table>
<thead>
<tr>
<th>Treatment</th>
<th>$d$(nm)</th>
<th>$\varepsilon_S$</th>
<th>$n_{ave}$</th>
<th>$\mu$ $(cm^2V^{-1}s^{-1})$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Oleic Acid</td>
<td>1.8</td>
<td>2</td>
<td>1.57</td>
<td>---</td>
</tr>
<tr>
<td>Aniline</td>
<td>0.8</td>
<td>2</td>
<td>2.2</td>
<td>---</td>
</tr>
<tr>
<td>Butlyamine</td>
<td>0.4</td>
<td>5.4</td>
<td>2.46</td>
<td>7.4</td>
</tr>
<tr>
<td>Ethylenediamine</td>
<td>0.4</td>
<td>16</td>
<td>2.62</td>
<td>47.0</td>
</tr>
<tr>
<td>Hydrazine</td>
<td>0.25</td>
<td>52</td>
<td>2.69</td>
<td>29.4</td>
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<tr>
<td>NaOH</td>
<td>0.1</td>
<td>1</td>
<td>2.4</td>
<td>35.0</td>
</tr>
</tbody>
</table>

Oleate Cap
$\text{CH}_3(\text{CH}_2)_7\text{HC}=$$\text{CH}(\text{CH}_2)_7\text{COOH}$
$D \sim 1.8$ nm

Aniline Cap
$\text{H}_2\text{NCH}_2\text{CH}_2\text{NH}_2$
$D \sim 0.8$ nm

Ethylenediamine
$\text{H}_2\text{NCH}_2\text{CH}_2\text{NH}_2$
$D = < 0.4$ nm

**Absorbance (O.D.)**

**Wavelength (nm)**

**FWHM = 49 meV**
Quantum Dot Solar Cells

**Potential Major Advantages of Using Quantum Dots**

- Enhanced photocurrent multiplication by MEG (Inverse Auger Process)
- Hot electron transport through minibands in QD arrays
- Slowed Cooling of High Energy (Hot) Electrons (phonon bottleneck)
Enhanced Photovoltaic Efficiency in Quantum Dot Solar Cells by Inverse Auger Effect (Impact Ionization)

One photon yields two e⁻–h⁺ pairs

A.J. Nozik, *Physica E* 14, 115 (2002);

**Quantum Dot Solar Cells**

**QD-Conducting Polymer Blend Solar Cell**

**QD-Sensitized Nanocrystalline TiO₂ Solar Cell**

**p-i-n QD Array Solar Cell**
Quantum Dot Sensitized TiO$_2$ Solar Cell

- Analogous to dye-sensitized TiO$_2$ solar cells
  - 10 to 20 µm film of NC TiO$_2$ (10-30 nm)
  - Ru dyes ⇒ Efficiency ~ 11%

- Advantages of QD’s as sensitizers:
  - possibility of slowed hot e\(^{-}\) cooling
  - possibility of impact ionization
  - tunable absorption
InAs QD Solar Cell Based on NC TiO₂
J-V Characteristic for 3.4 nm InAs QD Sensitized Solar Cell

![Graph showing J-V characteristic with current density vs. bias voltage for different light intensities (100 mW/cm², 5 mW/cm², and Dark). The graph indicates a maximum efficiency of η = 1.74%.](image-url)
Miniband Formation in 1-D Confined Quantum Films
QD Array in p-i-n Photon Conversion Cell

- e⁻ minibands
- h⁺ minibands
- <8 Å

n-i-p
PV Cell Based on QDs Dispersed in n-and p-type Organic Conducting Polymers
Summary/Conclusions

- Size quantization in semiconductors may greatly affect the relaxation dynamics of photoinduced carriers. These include:
  - slowed hot electron relaxation (partial phonon bottleneck)
  - enhanced Auger process (MEG)

- The theoretical and measured energy threshold for impact ionization in bulk semiconductors (e.g. Si, InAs, GaAs) is 4-5 times the band gap. Much lower thresholds are predicted for QDs because of the relaxation of the need to conserve momentum. The rate of exciton multiplication is also expected to be much faster in QDs (Auger processes $\alpha_1/d^6$)

- Very efficient exciton multiplication experimentally observed in PbSe, PbTe, PbS, InAs, and Si QDs; the threshold photon energy is $2E_g$. Up to 3 electrons per photon (300% QY) have been observed at sufficiently high photon energies ($\geq 4E_g$). A new model based on coherent superposition of multiexcitonic states is introduced to explain these results. Two excitons/photon yield over 90% of the efficiency benefit of carrier multiplication.

- Singlet fission is the molecular analog of MEG and also could yield enhanced solar photon conversion efficiencies. It had been observed in dimeric diphenylisobenzofurane. Single gap cells with carrier multiplication with MEG yield the same improvement for PV as 2-gap tandem PV cells. A tandem cell with SF and/or MEG is required to improve maximum efficiency for H2O splitting. Higher efficiency in SF cells for PV require a tandem cell configuration.
Summary/Conclusions - Continued

- Various configurations of Quantum Dot Solar Cells are suggested that could yield high conversion efficiencies:
  1. Nanocrystalline TiO2 sensitized with QDs
  2. QD arrays exhibiting 3-D miniband formation
  3. QDs embedded in a polymeric blend of electron- and hole-conducting polymers.
  4. SF molecular chromophores in a tandem cell for PV and photoelectrolysis

  THE DYNAMICS OF HOT ELECTRON and EXCITED MOLECULE COOLING, FORWARD AND INVERSE AUGER RECOMBINATION (MEG), AND ELECTRON TRANSFER CAN BE MODIFIED IN QD AND SF SYSTEMS TO POTENTIALLY ALLOW VERY EFFICIENT SOLAR PHOTON CONVERSION VIA EFFICIENT MULTIPLE EXCITON GENERATION